onsemi

Silicon Carbide (SiC) Diodes - EliteSiC, TO247-3, 10 A, 1200 V SiC Merged PiN-Schottky (MPS) Diode

UJ3D1210KS

Description

onsemi offers the 3rd generation of high performance SiC Merged-PiN-Schottky (MPS) diodes. With zero reverse recovery charge and 175 °C maximum junction temperature, these diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.

Features

- Maximum Operating Temperature of 175 °C
- Easy Paralleling
- Extremely Fast Switching Not Dependent on Temperature
- No Reverse or Forward Recovery
- Enhanced Surge Current Capability, MPS Structure
- Excellent Thermal Performance, Ag Sintered
- This Device is Pb-Free, Halogen Free and is RoHS Compliant

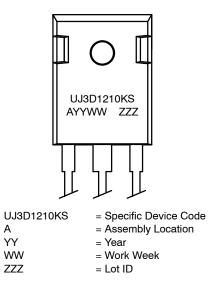
Typical Applications

- Power Converters
- Industrial Motor Drives
- Switch Mode Power Supplies
- Power Factor Correction Modules

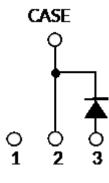


TO247-3 15.90x20.96x5.03, 5.44P CASE 340AK

MARKING DIAGRAM



PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

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MAXIMUM RATINGS

| Parameter | Symbol | Test Conditions | Value | Unit | |
|---|-----------------------------------|---|------------|------------------|--|
| DC Blocking Voltage | V _R | | 1200 | V | |
| Repetitive Peak Reverse Voltage, $T_J = 25 \ ^{\circ}C$ | V _{RRM} | | 1200 | V | |
| Surge Peak Reverse Voltage | V _{RSM} | | 1200 | V | |
| Maximum DC Forward Current | ١ _F | T _C = 158 °C | 10 | А | |
| Non-Repetitive Forward Surge Current Sine | I _{FSM} | T _C = 25 °C, t _p = 10 ms | 120 | А | |
| Half-wave | | T _C = 110 °C, t _p = 10 ms | 110 | | |
| Repetitive Forward Surge Current Sine | I _{FRM} | T _C = 25 °C, t _p = 10 ms | 56.7 | A | |
| Half-Wave, D=0.1 | | $\frac{T_{C} = 25 \text{ °C}, t_{p} = 10 \text{ ms}}{T_{C} = 110 \text{ °C}, t_{p} = 10 \text{ ms}}$ $I_{F,max} T_{C} = 25 \text{ °C}, t_{p} = 10 \mu\text{s}$ | 33.6 | | |
| Non-Repetitive Peak Forward Current | I _{F,max} | T _C = 25 °C, t _p = 10 μs | 720 | А | |
| | | T _C = 110 °C, t _p = 10 μs | 720 | | |
| i ² t Value | ∫i ² dt | T _C = 25 °C, t _p = 10 ms | 72 | A ² s | |
| | | T _C = 110 °C, t _p = 10 ms | 60 | | |
| Power Dissipation | P _{tot} | T _C = 25 °C | 234.4 | W | |
| | | T _C = 158 °C | 26.6 | | |
| Maximum Junction Temperature | T _{J,max} | | 175 | °C | |
| Operating and Storage Temperature | T _J , T _{STG} | | –55 to 175 | °C | |
| Soldering Temperatures, Wave Soldering Only Allowed at Leads | T _{sold} | 1.6 mm From Case for 10s | 260 | °C | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Parameter | Symbol | Test Conditions | Min | Тур | Мах | Unit |
|--------------------------------------|----------------|-----------------|-----|------|------|------|
| Thermal Resistance, Junction-to-Case | R_{\thetaJC} | | - | 0.49 | 0.64 | °C/W |

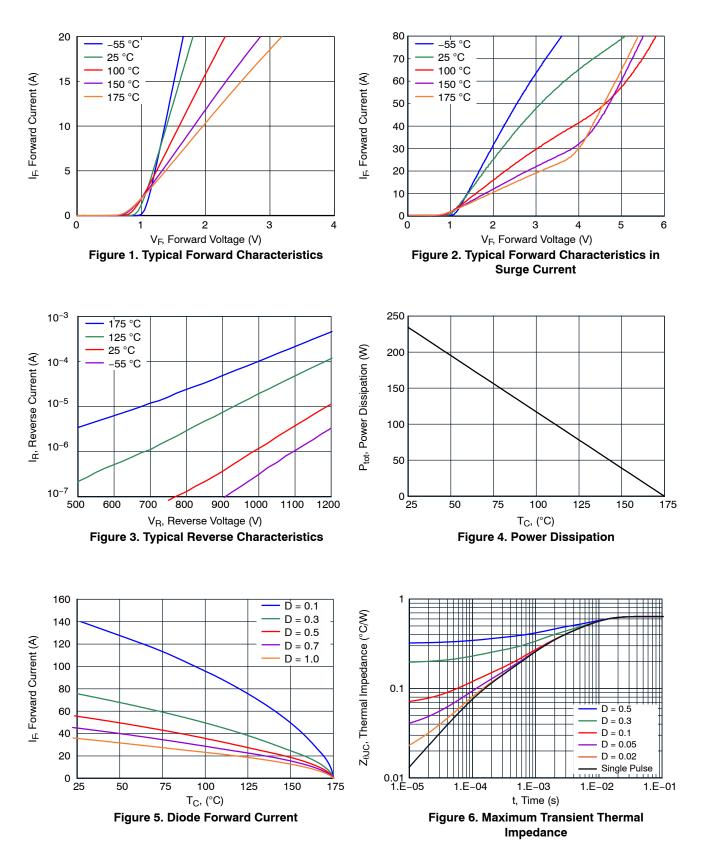
ELECTRICAL CHARACTERISTICS (T_J = +25 °C unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit |
|-------------------------------------|----------------|---|-----|------|-----|------|
| orward Voltage V _F | | I _F = 10 A, T _J = 25 °C | - | 1.4 | 1.6 | V |
| | | I _F = 10 A, T _J = 150 °C | - | 1.85 | 2.3 | |
| | | I _F = 10 A, T _J = 175 °C | - | 2 | 2.6 | |
| Reverse Current | I _R | V_{R} = 1200 V, T_{J} = 25 °C | - | 10 | 110 | μΑ |
| | | V _R = 1200 V, T _J = 175°C | - | 450 | - | |
| Total Gate Leakage Current (Note 1) | Q _C | V _R = 800 V | - | 51 | - | nC |
| Total Capacitance | С | V _R = 1 V, f = 1 MHz | - | 510 | - | pF |
| | | V _R = 400 V, f = 1 MHz | - | 48 | - | |
| | | V _R = 800 V, f = 1 MHz | - | 41 | - | 1 |
| Capacitance Stored Energy | E _C | V _R = 800 V | - | 15 | - | μJ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 1. Q_C is independent on T_J, di_F/dt, and I_F as shown in the application note AND90316/D.

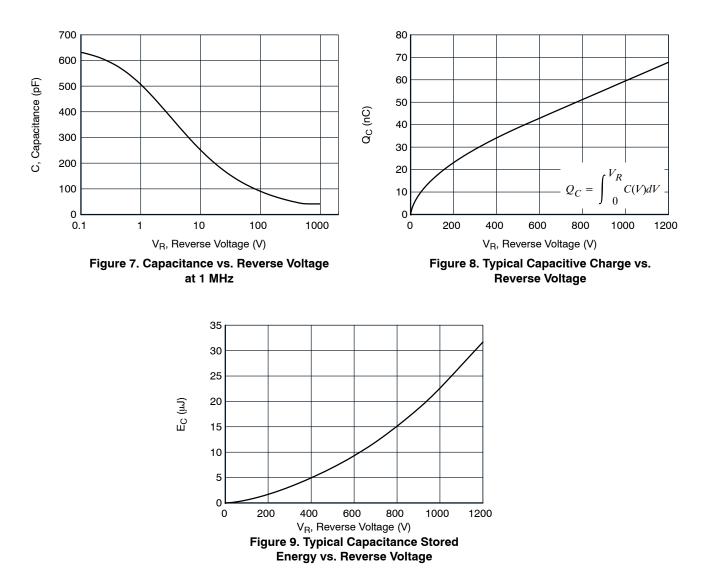
UJ3D1210KS

TYPICAL PERFORMANCE DIAGRAMS



UJ3D1210KS

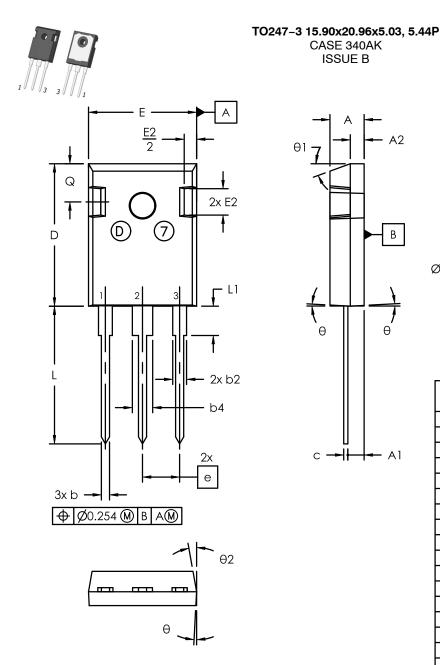
TYPICAL PERFORMANCE DIAGRAMS (continued)



ORDERING INFORMATION

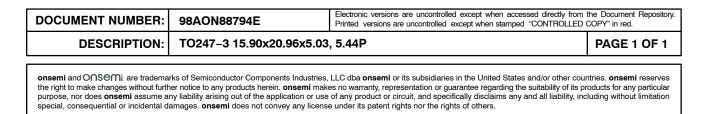
| Part Number | Marking | Package | Shipping |
|-------------|------------|--|------------|
| UJ3D1210KS | UJ3D1210KS | TO247-3 15.90x20.96x5.03, 5.44P (Pb-Free, Halogen Free) | 600 / Tube |

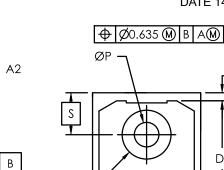
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NOTE:

- 1. Dimensioning and tolerancing as per ASME Y14.5 2018
- 2. Controlling dimension : millimeters
- 3. Package Outline in compliance with JEDEC standard var. AD.
- 4. Dimensions D & E does not include mold flash.
- ØP to have max draft angle of 1.7° to the top with max. hole 5. diameter of 3.91mm.





3

2

1

ØP1

θ

- A1

DATE 14 APR 2025

D2

Dl

| ◄- | —— E1 — | | | | | |
|-------------|-------------|----------|-------|--|--|--|
| SYM | millimeters | | | | | |
| 31/01 | MIN | NOM | MAX | | | |
| A | 4.70 | 5.03 | 5.31 | | | |
| A1 | 2.21 | 2.40 | 2.59 | | | |
| A2 | 1.50 | 2.03 | 2.49 | | | |
| b | 0.99 | 1.20 | 1.40 | | | |
| b2 | 1.65 | 2.03 | 2.39 | | | |
| b4 | 2.59 | 3.00 | 3.43 | | | |
| С | 0.38 | 0.60 | 0.89 | | | |
| C D | 20.70 | 20.96 | 21.46 | | | |
| D1 | 13.08 | _ | - | | | |
| D2 | 0.51 | 1.19 | 1.35 | | | |
| E | 15.49 | 15.90 | 16.26 | | | |
| е | | 5.44 BSC | | | | |
| E1 | 13.00 | 13.30 | 13.60 | | | |
| E2 | 3.43 | 3.89 | 5.20 | | | |
| L | 19.62 | 20.27 | 20.32 | | | |
| L1 | - | - | 4.50 | | | |
| ØP | 3.40 | 3.60 | 3.80 | | | |
| ØP1 | 7.06 | 7.19 | 7.39 | | | |
| Q S | 5.38 | 5.62 | 6.20 | | | |
| S | 6.15 BSC | | | | | |
| θ | 3° | | | | | |
| θ1 | 20° | | | | | |
| θ2 | 10° | | | | | |

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ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>